

Study of radiation hardness of un-doped Csl crystals and Silicon Photomultipliers for the Mu2e calorimeter

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Abstract

The Mu2e calorimeter is composed by 1400 un-doped CsI crystals coupled to large area UV extended Silicon Photomultipliers (SIPMs) arranged in two annular disks. This calorimeter has to provide precise information on energy, timing and position resolution. It should also be fast enough to handle the high rate background and it must operate and survive in a high radiation environment. Simulation studies estimated that, in the hottest regions, each crystal will absorb a dose of 300 Gy and will be exposed to a neutron fluency of 6 × 10¹¹ n/cm² in 3 years of running.

Test of un-doped CsI crystals irradiated up to 900 Gy and to a neutron fluency up to 9×10¹¹ n/cm² have been performed at CALLIOPE and FNG ENEA facilities in Italy. We present our study on the variation of light yield (LY) and longitudinal response uniformity (LRU) of these crystals after irradiation. The ionization dose does not modify LRU while a 20% reduction in LY is observed at 900 Gy. Similarly, the neutron flux causes an acceptable LY deterioration (< 15%).

A neutron irradiation test on different types of SIPMs (two different array models from FBK) have also been carried out by measuring the variation of the leakage current and the charge response to an ultraviolet led. We concluded that, in the experiment, we will need to cool down the SIPMs to 0 °C reduce the leakage current to an acceptable level.



Test @ CALLIOPE - Gamma Irradiation Facility (Casaccia, ENEA)



Test under vacuum and temperature dependences

- Leakage current of the SiPMs measured changing the temperature at three different V_{bias} values
- $(V_{op}, V_{op}-0.5 \text{ V}, V_{op}-1 \text{ Volt})$
- ◆ Measurement performed n vacuum (@ 10⁻⁴ Torr) with micro

TEC Peltier and PT100 temperature sensor • The data are related to a single ($6x6 \text{ mm}^2$) cell.

Results

• Leakage current reduction of a factor > 8 operating at 0°C

Conclusion

The determination of the LY and LRU changes for un-doped CsI crystals after irradiation dose and neutron fluency provides an important benchmark for the Mu2e calorimeter, where a high radiation environment is foreseen. Our tests show that doses up to 200 Gy do not modify LY and LRU for a (3 × 3 × 18) cm³ unwrapped CsI crystals from SICCAS coupled in air to an UV-extended PMT. After a total dose of 900 Gy, a 20% reduction in LY is obtained. Crystals from many vendors have also been irradiated with a neutron flux of 9 × 10¹¹ n/cm², corresponding to about 2 times the total flux expected for the hottest calorimeter regions in three years of running. At the end of the irradiation test, an acceptable deterioration for the LY has been observed and the LRU is maintained well below 10%. We have also tested the radiation damage of the Hamamatsu SPL and Micro Film SiPMs, with neutrons and photons by measuring their change in response and leakage current. The total neutron flux (2.2 x 10¹¹) causes a decreasement of the signal peak (and gain) and the increasement of the leakage current. A dose up to 200 Gy causes a negligible effect. Changes are still acceptable for the running condition in the experiment when cooling down the SiPM to a running temperature of ~ 0 °C.

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